In-flow and in-continuum refractive index sensing using a highly sensitive porous silicon ring resonator

Raffaele Caroselli¹

Salvador Ponce-Alcántara,¹ Francisco Prats Quilez,¹ David Martín Sánchez,¹ Luis Torrijos Morán,¹ Amadeu Griol Barres,¹ Laurent Bellieres,¹ Hanna Bandarenka,² Kseniya Girel,² Vitaly Bondarenko,² Jaime García-Rupérez,¹

¹Nanophotonics Technology Center, Universitat Politècnica de València, Camino de Vera s/n, 46022 Valencia, Spain

²Micro- and Nanoelectronics Department, Belarusian State University of Informatics and Radioelectronics, P. Brovka str. 6, 220013 Minsk, Belarus

rcaroselli@ntc.upv.es

Traditional sensing planar photonic structures based on a high index contrast configuration present a limitation affecting their sensitivity: only the evanescent field propagating outside the photonic structure is used for sensing purposes, while the majority of the optical field is confined within the structure itself. To overcome such limitation, we developed a highly sensitive photonic sensor based on a porous silicon ring resonator (PSRR). The porous silicon platform allows the infiltration of the target substance directly into the pores in order to obtain an increased sensitivity [1,2]. The photonic sensing structure was fabricated by using a high index contrast nanoporous silicon platform, consisting of a porous silicon double layer. A low porosity top layer was used to form the PSRR by e-beam lithography, whereas a high porosity bottom layer was used to confine light in the vertical direction (Fig. 1). The sensing performance of the PSRR was characterized by means of several refractive index sensing experiment. An opto-fluidic setup was developed to flow several solutions with different refractive indices over the photonic sensor and, at the same time, to monitor in-continuum the evolution of the PSRR spectrum (Fig. 2). PSRR presented a sensitivity of up to 439 nm/RIU (Refractive Index Unit). The average value of the noise observed in the experiments was

0.1 pm, leading to a limit of detection of only 2.2 $\cdot 10^{\text{-7}}$ RIU.

References

- F. A. Harraz, Sensors and Actuators B, 202 (2014) 897–912
- [2] O. Bisi, S. Ossicini, and L. Pavesi, Surface Science Reports, 38(1) (2000) 1–126

Figures

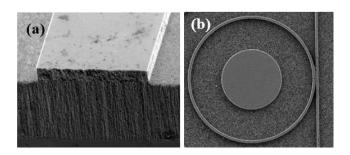


Figure 1: (a) 60°-sectional FE-SEM image of the 10µm-wide access waveguide. (b) Top-view image of the RR and the coupling waveguide.

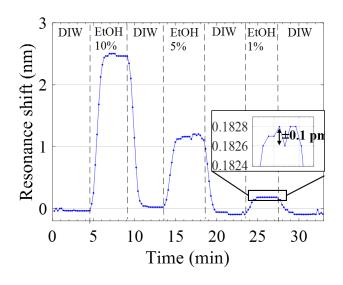


Figure 2: PSRR resonance wavelength shift time evolution.

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